



## USB PORT TRANSIENT SUPPRESSORS

### FEATURES

- Design to Protect Submicron 3-V or 5-V Circuits from Noise Transients
- Port ESD Protection Capability Exceeds:
  - 15-kV Human Body Model
  - 2-kV Machine Model
- Available in a WCSP Chip-Scale Package
- Stand-Off Voltage . . . 6 V Min
- Low Current Leakage . . . 1  $\mu$ A Max at 6 V
- Low Capacitance . . . 35 pF Typical

### DESCRIPTION

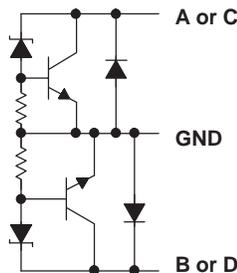
The SN65220 is a single transient voltage suppressor and the SN65240 and SN75240 are dual transient voltage suppressors designed to provide electrical noise transient protection to Universal Serial Bus (USB) 1.1 ports. Note that the input capacitance of the device makes it unsuitable for high-speed USB 2.0 applications.

Any cabled I/O can be subjected to electrical noise transients from various sources. These noise transients can cause damage to the USB transceiver and/or the USB ASIC if they are of sufficient magnitude and duration.

USB ports are typically implemented in 3-V or 5-V digital CMOS with very limited ESD protection. The SN65220, SN65240, and SN75240 can significantly increase the port ESD protection level and reduce the risk of damage to the circuits of the USB port.

The IEC1000-4-2 ESD performance of the SN65220, SN65240, and SN75240 is measured at the system level. Therefore, system design impacts the results of these tests. A high compliance level may be attained with proper board design and layout.

#### EQUIVALENT SCHEMATIC DIAGRAM

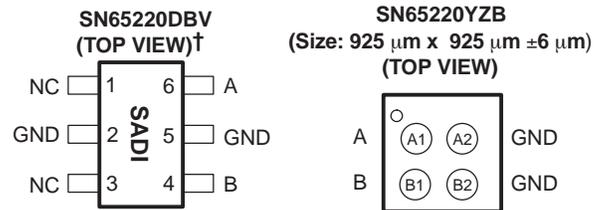


(One Suppressor Shown)

NOTE: All GND terminals should be connected to ground.

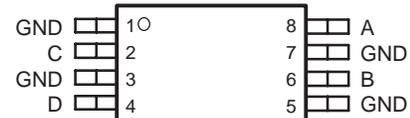
### APPLICATIONS

- USB 1.1 Host, Hub, or Peripheral Ports

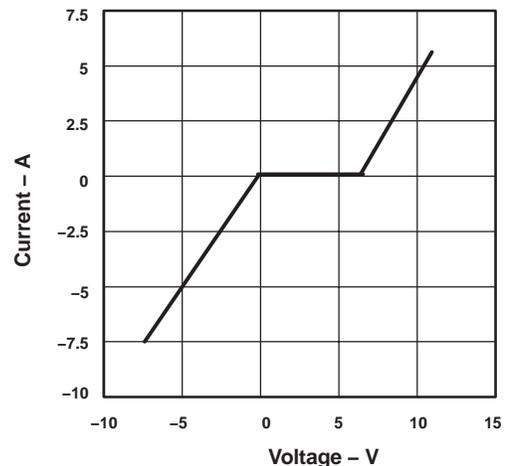


NC – No internal connection  
†When read horizontally, Pin 1 is the bottom left pin.

#### SN65240P, SN65240PW SN75240P, SN75240PW (TOP VIEW)



#### CURRENT vs VOLTAGE



NOTE A: Typical current versus voltage curve was derived using the IEC 1.2/50- $\mu$ s surge waveform.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

**IEC1000-4-2 COMPLIANCE LEVEL**

IEC1000-4-2 COMPLIANCE LEVEL	MAXIMUM TEST VOLTAGE	
	CONTACT DISCHARGE (kV)	AIR DISCHARGE (kV)
1	2	2
2	4	4
3	6	8
4	8	15

**PACKAGE/ORDERING INFORMATION**

PRODUCT	SUPRESSORS	T <sub>A</sub>	PACKAGE	PACKAGE DESIGNATOR	MARKED AS	ORDER NUMBER
SN65220	1	-40°C to 85°C	WCSP-4	YZB	NWP or 65220	SN65220YZBR (Reel)
						SN65220YZBT (Mini Reel)
			SOT23-6	DBV	SADI	SN65220DBVR (Mini Reel)
						SN65220DBVT (Mini Reel)
SN65240	2	-40°C to 85°C	DIP-8	P	A65240	SN65240P (Rail)
			TSSOP-8	PW		SN65240PW (Rail)
						SN65240PWR (Reel)
SN75240	2	0°C to 70°C	DIP-8	P	A75240	SN75240P (Rail)
			TSSOP-8	PW		SN75240PW (Rail)
						SN75240PWR (Reel)

**ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range unless otherwise noted<sup>(1)</sup>

	UNIT
Continuous power dissipation	See Dissipation Rating Table
Electrostatic discharge	15 kV <sup>(2)</sup> , 2 kV <sup>(3)</sup>
Peak power dissipation, P <sub>D(peak)</sub>	60 W
Peak forward surge current, I <sub>FSM</sub>	3 A
Peak reverse surge current, I <sub>RSM</sub>	-9 A
Storage temperature range, T <sub>stg</sub>	-65°C to 150°C

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) Human Body Model – Tested in accordance with JEDEC Standard 22, Test Method A114-A.

(3) Charged Device Model – Tested in accordance with JEDEC Standard 22, Test Method C101.

DISSIPATION RATING TABLE

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C‡	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
DBV	385 mW	3.1 mW/°C	246 mW	200 mW
P	1150 mW	9.2 mW/°C	736 mW	598 mW
PW	520 mW	4.2 mW/°C	331 mW	268 mW

‡ This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

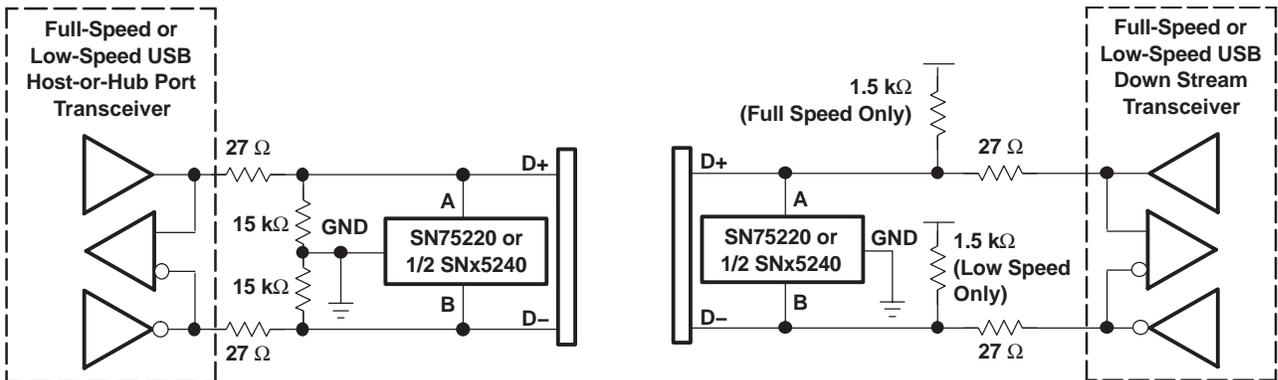
### recommended operating conditions

		MIN	MAX	UNIT
Operating free-air temperature, T <sub>A</sub>	SN75240	0	70	°C
	SN65220, SN65240	-40	85	

### electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I <sub>lkg</sub> Leakage current	V <sub>I</sub> = 6 V at A, B, C, or D terminals			1	μA
V <sub>(BR)</sub> Breakdown voltage	V <sub>I</sub> = 1 mA at A, B, C, or D terminals	6.5	7	8	V
C <sub>IN</sub> Input capacitance to ground	V <sub>I</sub> = 0.4 sin(4E6πt) + 0.5 V		35		pF

### APPLICATION INFORMATION



**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN65220DBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65220DBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65220DBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65220DBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65220YZBR	ACTIVE	DSBGA	YZB	4	3000	TBD	Call TI	Level-1-260C-UNLIM
SN65220YZBT	ACTIVE	DSBGA	YZB	4	250	TBD	Call TI	Level-1-260C-UNLIM
SN65240P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN65240PE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN65240PW	ACTIVE	TSSOP	PW	8	150	TBD	CU NIPDAU	Level-1-220C-UNLIM
SN65240PWR	ACTIVE	TSSOP	PW	8	2000	TBD	CU NIPDAU	Level-1-220C-UNLIM
SN75240P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN75240PE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN75240PW	ACTIVE	TSSOP	PW	8	150	TBD	CU NIPDAU	Level-1-220C-UNLIM
SN75240PWLE	OBSOLETE	TSSOP	PW	8		TBD	Call TI	Call TI
SN75240PWR	ACTIVE	TSSOP	PW	8	2000	TBD	CU NIPDAU	Level-1-220C-UNLIM
SN75240PWRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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